NSN 5962-01-481-3781

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
1430-01-378-6963
Features Provided:
Ultraviolet erasable and monolithic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Product Name:
Microcircuit, digital, memory, cmos, 8k x 8 uv eprom, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
35.00 nanoseconds af output megawatts
Memory Device Type:
Eprom
Memory Capacity:
8k x 8
Special Features:
Microcircuit shall be in accordance with requirements of 5962-8751508lx; except for programming by downloading bit patterns contained or
master prom described on software control drawing 1003288; p/n 1003288-2 has incorporated new firmware software; w/s: avenger
system
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0